TOSHIBA CMOS Digital Integrated Circuit   Silicon Monolithic

TC74VHC125F,TC74VHC125FN,TC74VHC125FT,TC74VHC125FK
TC74VHC126F,TC74VHC126FN,TC74VHC126FT,TC74VHC126FK

TC74VHC125F/FN/FT/FK   Quad Bus Buffer

TC74VHC126F/FN/FT/FK   Quad Bus Buffer

Note: xxxFN (JEDEC SOP) is not available in Japan.

The TC74VHC125/126 are high speed CMOS QUAD BUS BUFFERs fabricated with silicon gate C^2MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Shottky TTL while maintaining the CMOS low power dissipation.

The TC74VHC125 requires the 3-state control input $\overline{G}$ to be set high to place the output into the high impedance state, whereas the TC74VHC126 requires the control input G to be set low to place the output into high impedance.

An input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and two supply systems such as battery back up.

This circuit prevents device destruction due to mismatched supply and input voltages.

Features

- High speed: t_{pd} = 3.8 ns (typ.) at V_{CC} = 5 V
- Low power dissipation: I_{CC} = 4 μA (max) at Ta = 25°C
- High noise immunity: V_{NIH} = V_{NIL} = 28% V_{CC} (min)
- Power down protection is provided on all inputs.
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Wide operating voltage range: $V_{CC (opr)}$ = 2 to 5.5 V
- Low noise: V_{OLP} = 0.8 V (max)
- Pin and function compatible with 74ALS125/126

Weight
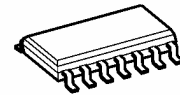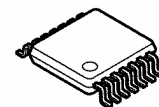|	
SOP14-P-300-1.27A	: 0.18 g (typ.)
SOP14-P-300-1.27	: 0.18 g (typ.)
SOL14-P-150-1.27	: 0.12 g (typ.)
TSSOP14-P-0044-0.65A	: 0.06 g (typ.)
VSSOP14-P-0030-0.50	: 0.02 g (typ.)

TC74VHC125F, TC74VHC126F
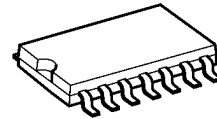
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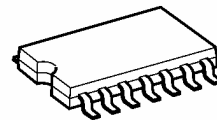
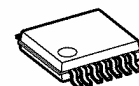SOP14-P-300-1.27
TC74VHC125FN, TC74VHC126FN
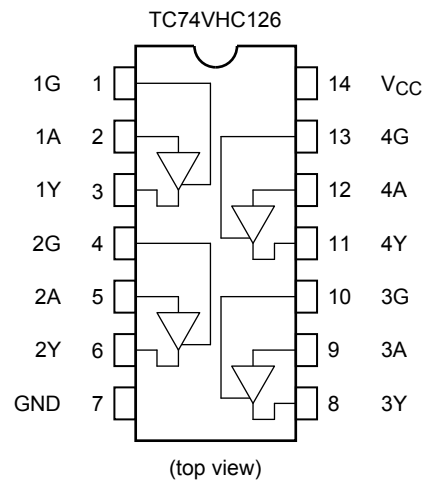

SOL14-P-150-1.27
TC74VHC125FT, TC74VHC126FT

TSSOP14-P-0044-0.65A
TC74VHC125FK, TC74VHC126FK

VSSOP14-P-0030-0.50

Pin Assignment
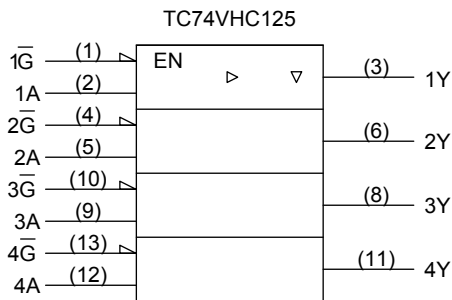
TC74VHC125

1$\overline{\text{G}}$	1		14	V$_{CC}$
1A	2		13	4$\overline{\text{G}}$
1Y	3		12	4A
2$\overline{\text{G}}$	4		11	4Y
2A	5		10	3$\overline{\text{G}}$
2Y	6		9	3A
GND	7		8	3Y

(top view)

TC74VHC126

1G	1		14	V$_{CC}$
1A	2		13	4G
1Y	3		12	4A
2G	4		11	4Y
2A	5		10	3G
2Y	6		9	3A
GND	7		8	3Y

(top view)

IEC Logic Symbol

TC74VHC125

1$\overline{\text{G}}$ (1)	EN	(3) 1Y
1A (2)		
2$\overline{\text{G}}$ (4)		(6) 2Y
2A (5)		
3$\overline{\text{G}}$ (10)		(8) 3Y
3A (9)		
4$\overline{\text{G}}$ (13)		(11) 4Y
4A (12)		

TC74VHC126

1G (1)	EN	(3) 1Y
1A (2)		
2G (4)		(6) 2Y
2A (5)		
3G (10)		(8) 3Y
3A (9)		
4G (13)		(11) 4Y
4A (12)		
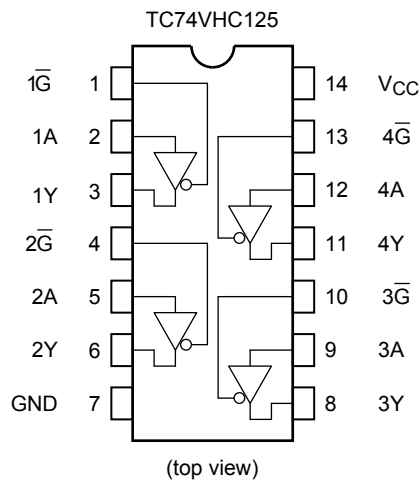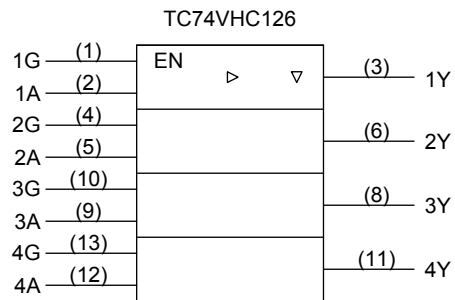
Truth Table

TC74VHC125

Inputs		Output
$\overline{\text{G}}$	A	Y
H	X	Z
L	L	L
L	H	H

X: Don't care

Z: High impedance

TC74VHC126

Inputs		Output
G	A	Y
L	X	Z
H	L	L
H	H	H

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	−0.5 to 7.0	V
DC input voltage	V_{IN}	−0.5 to 7.0	V
DC output voltage	V_{OUT}	−0.5 to V_{CC} + 0.5	V
Input diode current	I_{IK}	−20	mA
Output diode current	I_{OK}	±20	mA
DC output current	I_{OUT}	±25	mA
DC V_{CC}/ground current	I_{CC}	±50	mA
Power dissipation	P_D	180	mW
Storage temperature	T_{stg}	−65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Recommended Operating Conditions (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2.0 to 5.5	V
Input voltage	V_{IN}	0 to 5.5	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	−40 to 85	°C
Input rise and fall time	dt/dv	0 to 100 (V_{CC} = 3.3 ± 0.3 V) 0 to 20 (V_{CC} = 5 ± 0.5 V)	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics	Symbol	Test Condition		V_{CC} (V)	Ta = 25°C			Ta = −40 to 85°C		Unit
					Min	Typ.	Max	Min	Max	
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	1.50	—	V
				3.0 to 5.5	$V_{CC} \times 0.7$	—	—	$V_{CC} \times 0.7$	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	—	0.50	V
				3.0 to 5.5	—	—	$V_{CC} \times 0.3$	—	$V_{CC} \times 0.3$	
High-level output voltage	V_{OH}	V_{IN} = V_{IH} or V_{IL}	$I_{OH} = -50\ \mu A$	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
				4.5	4.4	4.5	—	4.4	—	
			$I_{OH} = -4\ mA$	3.0	2.58	—	—	2.48	—	
			$I_{OH} = -8\ mA$	4.5	3.94	—	—	3.80	—	
Low-level output voltage	V_{OL}	V_{IN} = V_{IH} or V_{IL}	$I_{OL} = 50\ \mu A$	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
				4.5	—	0.0	0.1	—	0.1	
			$I_{OL} = 4\ mA$	3.0	—	—	0.36	—	0.44	
			$I_{OL} = 8\ mA$	4.5	—	—	0.36	—	0.44	
3-state output off-state current	I_{OZ}	V_{IN} = V_{IH} or V_{IL} V_{OUT} = V_{CC} or GND		5.5	—	—	±0.25	—	±2.50	μA
Input leakage current	I_{IN}	V_{IN} = 5.5 V or GND		0 to 5.5	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I_{CC}	V_{IN} = V_{CC} or GND		5.5	—	—	4.0	—	40.0	μA

AC Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition			Ta = 25°C			Ta = −40 to 85°C		Unit
		V_{CC} (V)	C_L (pF)		Min	Typ.	Max	Min	Max	
Propagation delay time	t_{pLH} t_{pHL}	—	3.3 ± 0.3	15	—	5.6	8.0	1.0	9.5	ns
				50	—	8.1	11.5	1.0	13.0	
			5.0 ± 0.5	15	—	3.8	5.5	1.0	6.5	
				50	—	5.3	7.5	1.0	8.5	
Output enable time	t_{pZL} t_{pZH}	$R_L = 1$ kΩ	3.3 ± 0.3	15	—	5.4	8.0	1.0	9.5	ns
				50	—	7.9	11.5	1.0	13.0	
			5.0 ± 0.5	15	—	3.6	5.1	1.0	6.0	
				50	—	5.1	7.1	1.0	8.0	
Output disable time	t_{pLZ} t_{pHZ}	$R_L = 1$ kΩ	3.3 ± 0.3	50	—	9.5	13.2	1.0	15.0	ns
			5.0 ± 0.5	50	—	6.1	8.8	1.0	10.0	
Output to output skew	t_{osLH} t_{osHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5	ns
			5.0 ± 0.5	50	—		1.0	—	1.0	
Input capacitance	C_{IN}	—			—	4	10	—	10	pF
Output capacitance	C_{OUT}	—			—	6	—	—	—	pF
Power dissipation capacitance (Note 2)	C_{PD}	TC74VHC125			—	14	—	—	—	pF
		TC74VHC126			—	15	—	—	—	

Note 1: Parameter guaranteed by design.

$$t_{osLH} = |t_{pLHm} - t_{pLHn}|, \ t_{osHL} = |t_{pHLm} - t_{pHLn}|$$

Note 2: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC \, (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per gate)}$$

Noise Characteristics (input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Unit
			V_{CC} (V)	Typ.	Limit	
Quiet output maximum dynamic V_{OL}	V_{OLP}	$C_L = 50$ pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V_{OL}	V_{OLV}	$C_L = 50$ pF	5.0	−0.3	−0.8	V
Minimum high level dynamic input voltage	V_{IHD}	$C_L = 50$ pF	5.0	—	3.5	V
Maximum low level dynamic input voltage	V_{ILD}	$C_L = 50$ pF	5.0	—	1.5	V

Input Equivalent Circuit
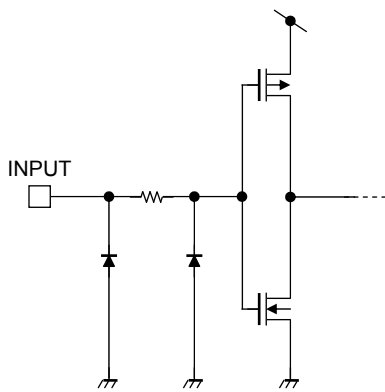
Package Dimensions

SOP14-P-300-1.27A   Unit: mm
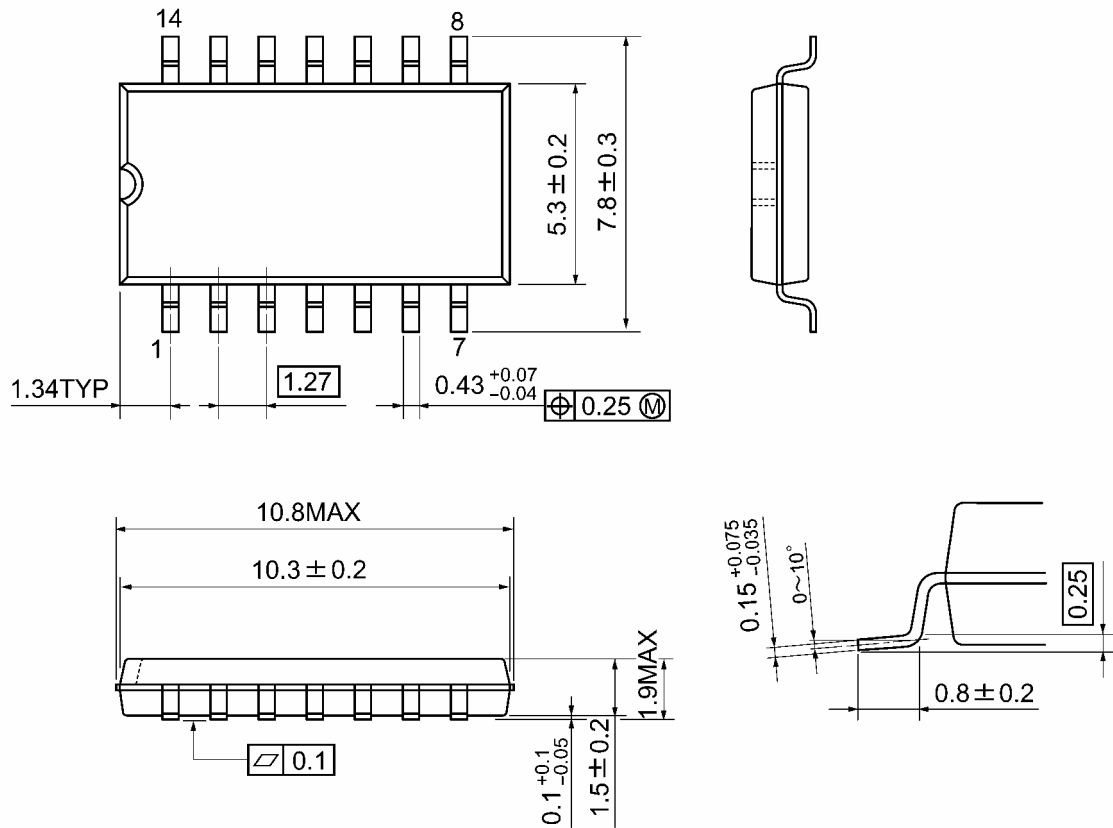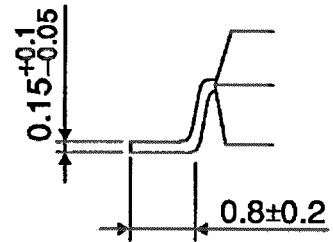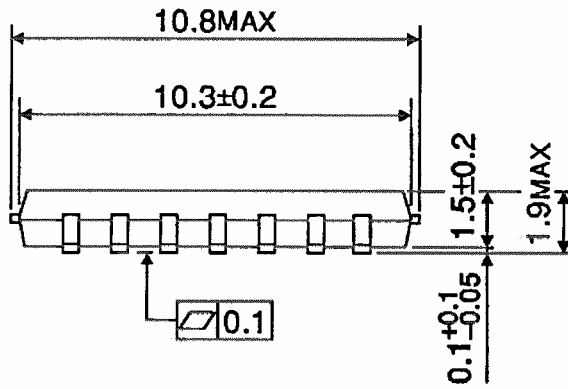

Weight: 0.18 g (typ.)

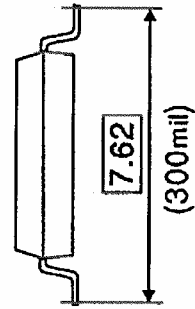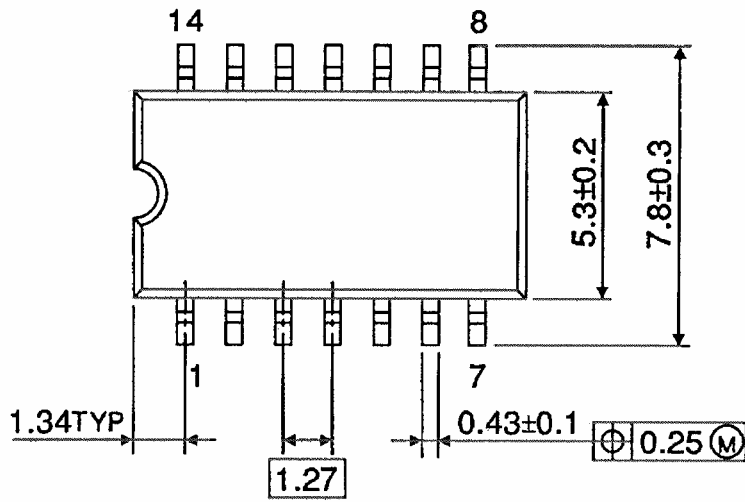## Package Dimensions

SOP14-P-300-1.27   Unit : mm
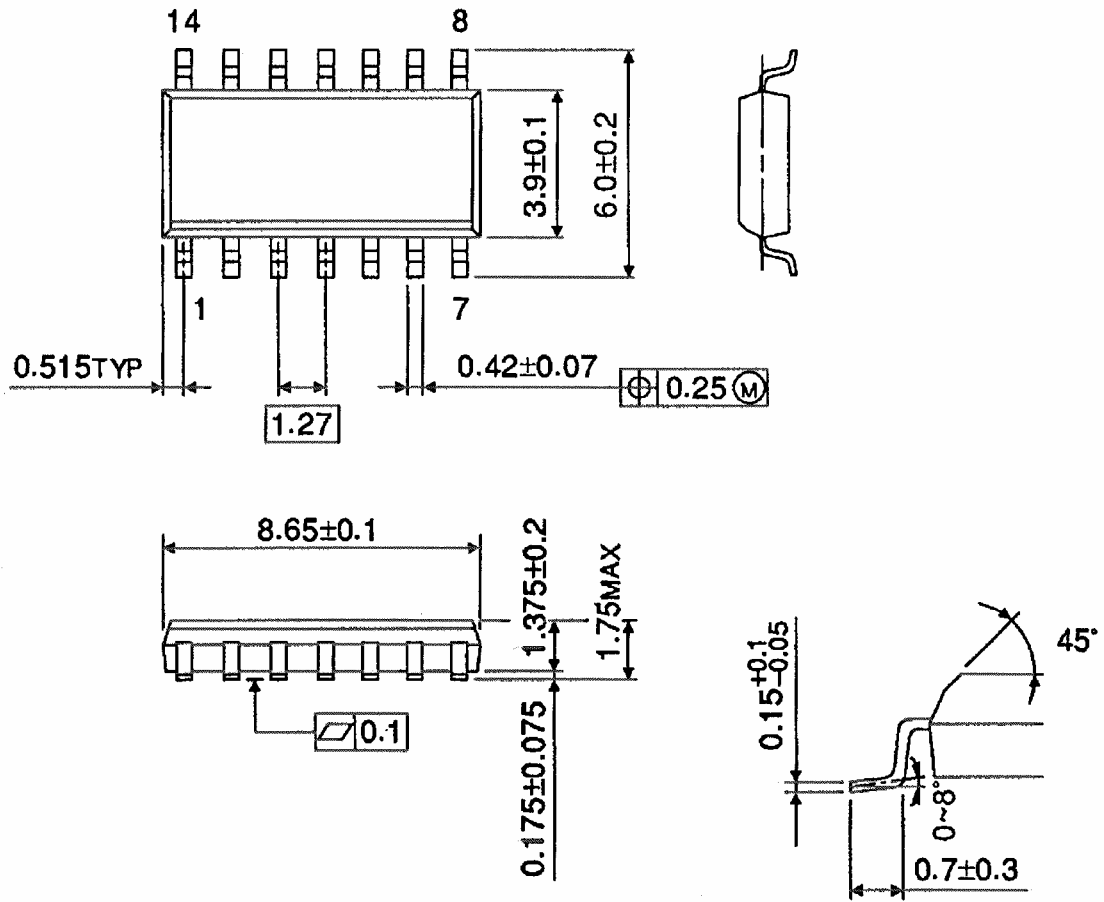

Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL14-P-150-1.27   Unit : mm

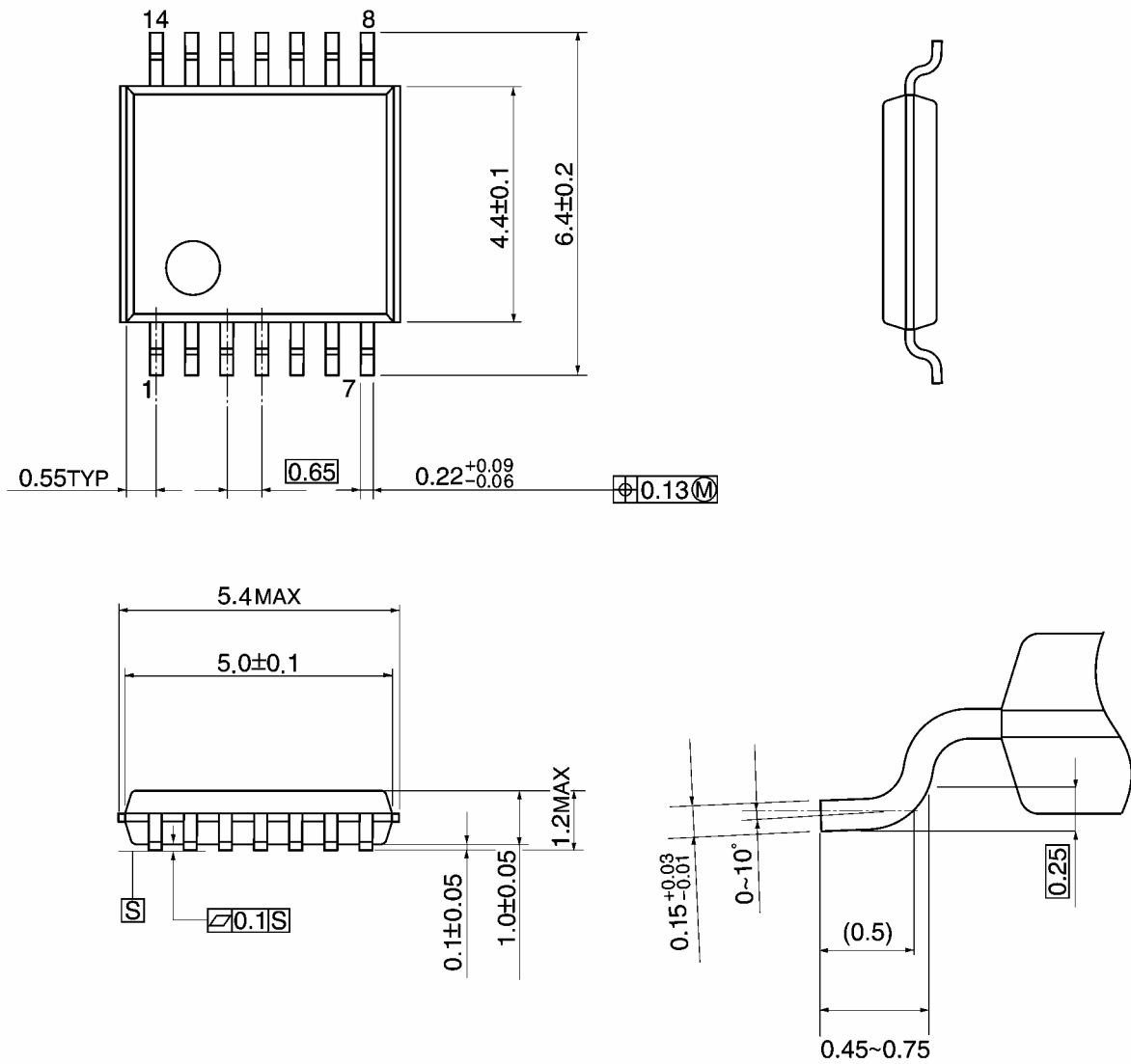Note: This package is not available in Japan.

Weight: 0.12 g (typ.)
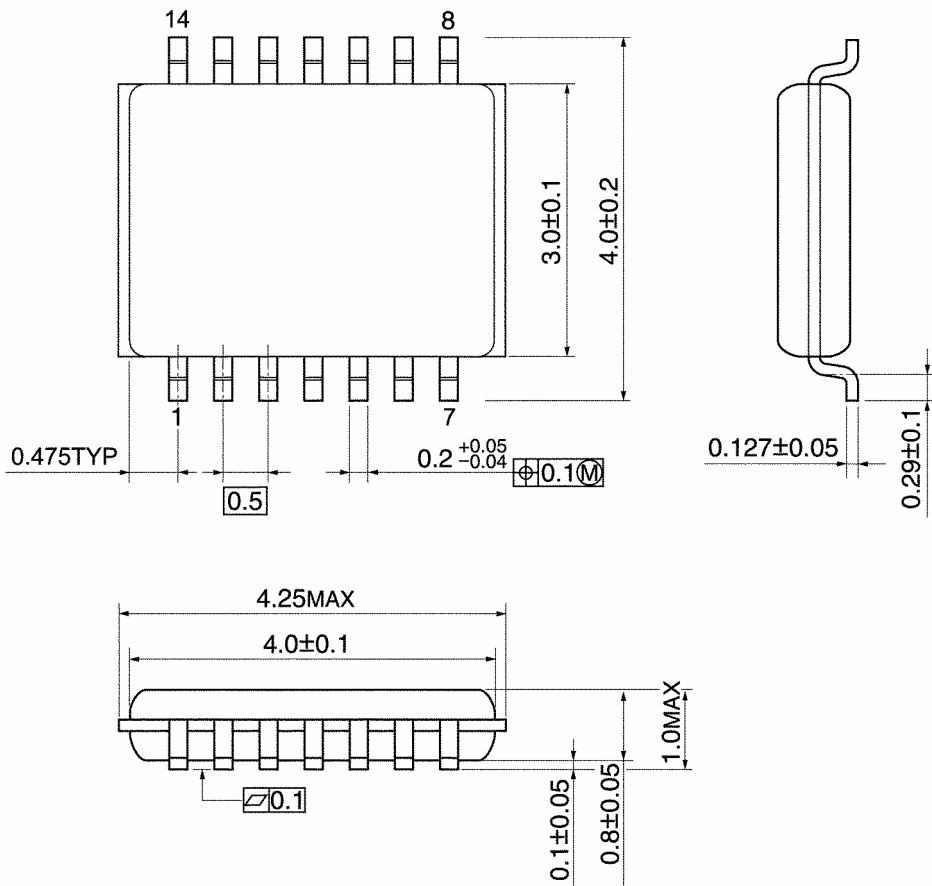
Package Dimensions

TSSOP14-P-0044-0.65A

Unit: mm

Weight: 0.06 g (typ.)

Package Dimensions

VSSOP14-P-0030-0.50   Unit: mm

14   8

1   7

0.475TYP

0.5

$0.2^{+0.05}_{-0.04}$

⊕ 0.1 Ⓜ

3.0±0.1

4.0±0.2

0.127±0.05

0.29±0.1

4.25MAX

4.0±0.1

1.0MAX

0.1±0.05

0.8±0.05

◹ 0.1

Weight: 0.02 g (typ.)

Note: Lead (Pb)-Free Packages

SOP14-P-300-1.27A   SOL14-P-150-1.27   TSSOP14-P-0044-0.65A   VSSOP14-P-0030-0.50

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20070701-EN

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